

Excellent Integrated System Limited

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Murata Electronics North America RO3104E

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Distributor of Murata Electronics North America: Excellent Integrated System Limited Datasheet of RO3104E - SAW RESONATR 303.825MHZ SM3030-6

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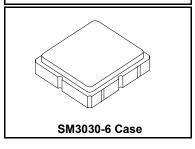


INNOVATOR IN ELECTRONICS

RFM products are now Murata products.

RO3104E

303.825 MHz SAW Resonator



- Ideal for 303.825 MHz Remote Control and Security Transmitters
- Very Low Series Resistance
- · Quartz Frequency Stability
- Miniature 3.0 x 3.0 mm Surface-mount Case
- Complies with Directive 2002/95/EC (RoHS)

The RO3104E is a true one-port, surface-acoustic-wave (SAW) resonator in a surface-mount ceramic case. It provides reliable, fundamental mode quartz frequency stabilization of fixed-frequency transmitters operating at 303.825 MHz. This SAW is designed specifically for AM transmitters used in wireless security and remote control applications.

Absolute Maximum Ratings

Rating	Value	Units
CW RF Power Dissipation (See Typical Test Circuit)	0	dBm
DC Voltage Between Terminals (Observe ESD Precautions)	12	VDC
Case Temperature	-40 to +85	°C
Soldering Temperature (10 seconds, 5 cycles maximum)	+260	°C

Electrical Characteristics

Characteristic		Sym	Notes	Minimum	Typical	Maximum	Units
Frequency, +25 °C	Nominal Frequency	f _C	2, 3, 4, 5	303.750		303.900	MHz
	Tolerance from 303.825 MHz	Δf _C	2, 3, 4, 3			±75	kHz
Insertion Loss		IL	2, 5, 6		1.35	2.0	dB
Quality Factor	Unloaded Q	Q _U	5, 6, 7		10000		
	50 Ω Loaded Q	Q_L	5, 6, 7		1400		
Temperature Stability	Turnover Temperature	T _O		10	25	40	°C
	Turnover Frequency	f _O	6, 7, 8		f _C		
	Frequency Temperature Coefficient	FTC			0.032		ppm/°C ²
Frequency Aging	Absolute Value during the First Year	f _A	1, 6		10		ppm/yr
DC Insulation Resistance between Any Two Terminals			5	1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R _M	5, 6, 7, 9.		16		Ω
	Motional Inductance	L _M			85		μH
	Motional Capacitance	C _M	, ,		3.2		fF
	Transducer Static Capacitance	Co	5, 6, 9		3.2		pF
Test Fixture Shunt Inductance		L _{TEST}	2, 7		85		nH
Lid Symbolization		690 // YWWS					
Standard Reel Quantity	Reel Size 7 Inch		10		500 Pieces/Re	el	
	Reel Size 13 Inch		3000 Pieces/Reel				

CAUTION: Electrostatic Sensitive Device. Observe precautions for handling.

- Frequency aging is the change in f_C with time and is specified at +65 °C or less. Aging may exceed the specification for prolonged temperatures above +65 °C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
- 2. The center frequency, f_C, is measured at the minimum insertion loss point, IL_{MIN}, with the resonator in the 50 Ω test system (VSWR ≤ 1.2:1). The shunt inductance, L_{TEST}, is tuned for parallel resonance with C_O at f_C. Typically, f_{OSCILLATOR} or f_{TRANSMITTER} is approximately equal to the resonator f_C.
- One or more of the following United States patents apply: 4,454,488 and 4,616,197.
- Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacture.
- 5. Unless noted otherwise, case temperature T_C = +25 ± 2 °C.
- The design, manufacturing process, and specifications of this device are

- subject to change. 7. Derived mathematically from one or more of the following directly measured parameters: f_C , IL, 3 dB bandwidth, f_C versus T_C , and C_O .
- Turnover temperature, T_O, is the temperature of maximum (or turnover) frequency, f_O. The nominal frequency at any case temperature, T_C, may be calculated from: f = f_O [1 FTC (T_O -T_C)²]. Typically oscillator T_O is approximately equal to the specified resonator T_O.
- 9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance $C_{\rm O}$ is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can by calculated as: $C_{\rm P}\approx C_{\rm O}$ 0.05 pF.
- 10. Tape and Reel Standard Per ANSI / EIA 481.

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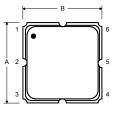
Datasheet of RO3104E - SAW RESONATR 303.825MHZ SM3030-6

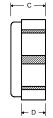
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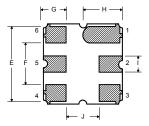
Electrical Connections

The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit.

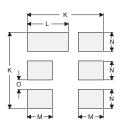
Pin	Connection		
1	NC		
2	Terminal		
3	NC		
4	NC		
5	Terminal		
6	NC		







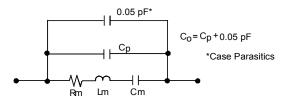




Case and Typical PCB Land Dimensions

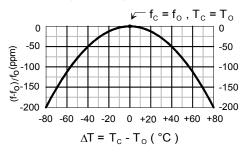
Ref	mm			Inches			
	Min	Nom	Max	Min	Nom	Max	
Α	2.87	3.00	3.13	0.113	0.118	0.123	
В	2.87	3.00	3.13	0.113	0.118	0.123	
С	1.12	1.25	1.38	0.044	0.049	0.054	
D	0.77	0.90	1.03	0.030	0.035	0.040	
E	2.67	2.80	2.93	0.105	0.110	0.115	
F	1.47	1.60	1.73	0.058	0.063	0.068	
G	0.72	0.85	0.98	0.028	0.033	0.038	
Н	1.37	1.50	1.63	0.054	0.059	0.064	
I	0.47	0.60	0.73	0.019	0.024	0.029	
J	1.17	1.30	1.43	0.046	0.051	0.056	
K		3.20			0.126		
L		1.70			0.067		
M		1.05			0.041		
N		0.81			0.032		
0		0.38			0.015		

Equivalent RLC Model



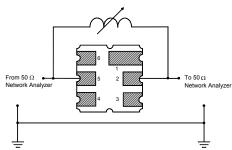
Temperature Characteristics

The curve shown accounts for resonator contribution only and does not include external LC component temperature effects.

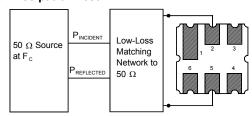


Characterization Test Circuit

Inductor L_{TEST} is tuned to resonate with the static capacitance, C_{O} , at F_{C} .



Power Dissipation Test



Example Application Circuits

Typical Low-Power Transmitter Application

